

NPN-General use transistor 225mW 50m 20V

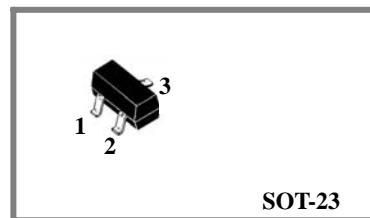
Quality level and executive standard

◆“G”level

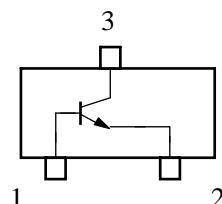
QZJ840611 Q/FRQZJ123-2007

◆the II level of national standard

GB4589.1-89 GB/T 12560-1999 Q/FR124-2007



Applications: Can be used for switching and amplifying in various electrical and electronic equipments.



Max ratings

| Parameters | Symbol | Rating | Unit |
|---|-----------|---------|------|
| Collector-emitter voltage ($I_B=0$) | V_{CEO} | 20 | V |
| Collector-base voltage ($I_E=0$) | V_{CBO} | 30 | V |
| Emitter – base voltage ($I_C=0$) | V_{EBO} | 3 | V |
| Collector current | I_C | 50 | mA |
| Total power dissipation ($T_A=25^\circ\text{C}$) [*] | P_{tot} | 225 | mW |
| Max junction temperature | T_{jm} | 150 | °C |
| Storage temperature | T_{stg} | -55~150 | °C |

* mounted on printed circuit board.

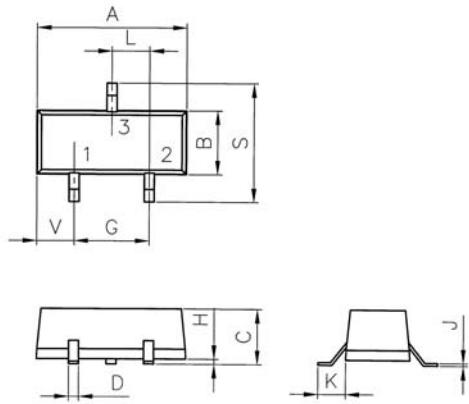
Characteristics (Unless otherwise specified, $T_A=25^\circ\text{C}$)

| Parameters | symbol | Test condition | min | typ | max | unit |
|--|------------------------------|--|-----|-----|-----|------|
| Collector-emitter breakdown voltage | $V_{(BR)CEO}$ | $I_C=3\text{mA}, I_B=0$ | 20 | — | — | V |
| Collector-base breakdown voltage | $V_{(BR)CBO}$ | $I_C=100\mu\text{A}, I_E=0$ | 30 | — | — | V |
| Emitter– base breakdown voltage | $V_{(BR)EBO}$ | $I_E=100\mu\text{A}, I_C=0$ | 3 | — | — | V |
| Forward current transfer ratio ¹⁾ | h_{FE} | $V_{CE}=1\text{V}; I_C=3\text{mA}$ | 40 | — | 180 | — |
| Collector-base cutoff current | I_{CBO} | $V_{CB}=15\text{V}, I_E=0$ | — | — | 50 | nA |
| Collector-emitter saturation voltage ¹⁾ | $V_{CE \langle sat \rangle}$ | $I_C=10\text{mA}, I_B=1\text{mA}$ | — | — | 0.4 | V |
| Base-emitter saturation voltage ¹⁾ | $V_{BE \langle sat \rangle}$ | $I_C=10\text{mA}, I_B=1\text{mA}$ | — | — | 1 | V |
| Transition frequency | f_T | $I_C=4\text{mA}, V_{CE}=10\text{V}, f=100\text{MHz}$ | 600 | — | — | MHz |

Classification of hFE

| Marking | F12 | F13 | F14 |
|-----------|----------|-----------|-----------|
| hFE Range | 40 to 80 | 60 to 120 | 90 to 180 |

Outline dimensions (see fig.1)



| SOT-23 | | |
|--------|------|------|
| | min | max |
| A | 2.80 | 3.04 |
| B | 1.20 | 1.40 |
| C | 0.89 | 1.13 |
| D | 0.30 | 0.50 |
| G | 1.78 | 2.04 |
| H | 0.01 | 0.10 |
| J | 0.08 | 0.18 |
| K | 0.45 | 0.60 |
| L | 0.89 | 1.02 |
| S | 2.10 | 2.50 |
| V | 0.42 | 0.60 |

Typical curve

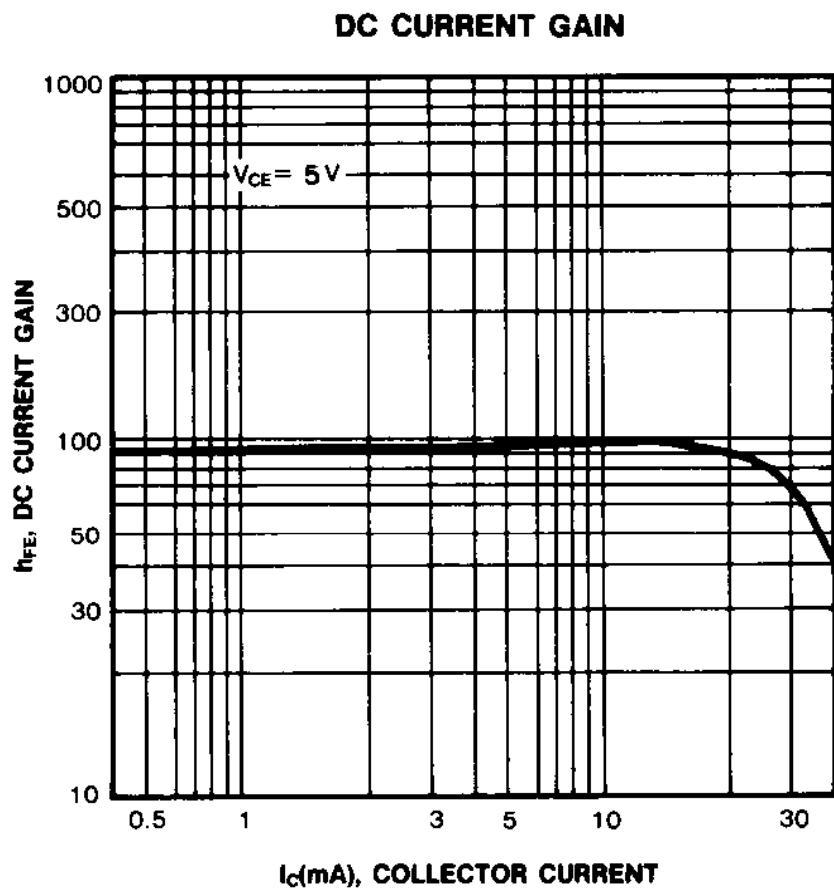


Fig.2 DC current gain; typical values.